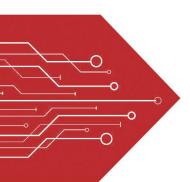
## MSKSEMI















**ESD** 

TVS

TSS

MOV

GDT

**PLED** 

# Broduct data sheet



Semiconductor

Compiance

## VOLTAGE RANGE 50 to 600 Volts CURRENT

3.0 Amperes



**SMB** 

#### **FEATURES**

- \* Ideal for surface mount applications
- \* Easy pick and place
- \* Built-in strain relief
- \* Low forward voltage drop

#### **MECHANICAL DATA**

- \* Case: Molded plastic
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Metallurgically bonded construction
- \* Polarity: Color band denotes cathode end
- \* Mounting position: Any
- \* Weight: 0.093 grams

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwies specified. Single phase half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

P/N(MARK)		ES3AB	ES3BB	ES3CB	ES3DB	ES3EB	ES3GB	ES3JB	UNITS
Maximum Recurrent Peak Reverse Voltage		50	100	150	200	300	400	600	V
Maximum RMS Voltage		35	70	105	140	210	280	420	V
Maximum DC Blocking Voltage		50	100	150	200	300	400	600	V
Maximum Average Forward Rectified (	Current								
.375"(9.5mm) Lead Length at Ta=55℃					3.0				Α
Peak Forward Surge Current, 8.3 ms single half sine-wave									
superimposed on rated load (JEDEC method)					80				Α
Maximum Instantaneous Forward Voltage at 3.0A			1.	0		1.	.4	1.7	V
Maximum DC Reverse Current	Ta=25°C				5.0				uA
at Rated DC Blocking Voltage	Ta=100°C				50				uA
Maximum Reverse Recovery Time (Note 1)			35				nS		
Typical Junction Capacitance (Note 2)			60				pF		
Operating and Storage Temperature Range TJ, Tstg			-65—+150					°C	

#### NOTES:

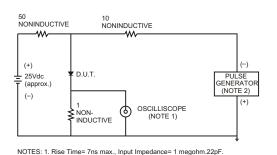
- 1. Reverse Recovery Time test condition: IF=0.5A, IR=1.0A, IRR=0.25A
- 2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.





#### RATING AND CHARACTERISTIC CURVES (ES3AB THRU ES3JB)

#### FIG.1- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



2. Rise Time= 10ns max., Source Impedance= 50 ohms.

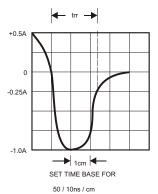


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

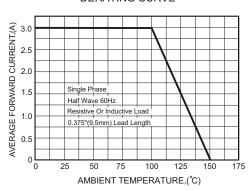


FIG.3-TYPICAL FORWARD

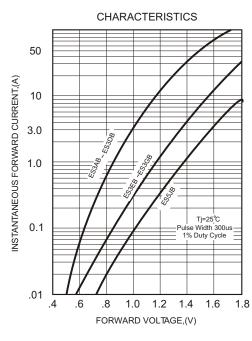


FIG.4-TYPICAL REVERSE CHARACTERISTICS 50 10 REVERSE LEAKAGE CURRENT, (A) 3.0 1.0 Tj=100°C 0.1 20 40 60 80 100 120 PERCENT OF RATED PEAK REVERSE VOLTAGE,(%)

FIG.5-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

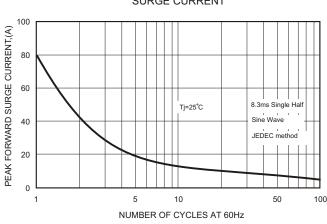
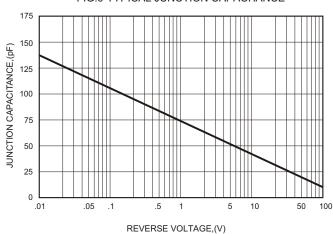


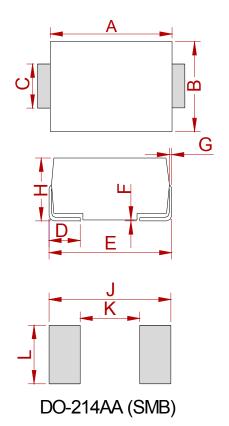
FIG.6-TYPICAL JUNCTION CAPACITANCE





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## **PACKAGE MECHANICAL DATA**



	1						
	Dimensions						
Ref.	Millir	neters	Inches				
	Min.	Max.	Min.	Max.			
Α	4.25	4.75	0.167	0.187			
В	3.30	3.94	0.130	0.155			
С	1.85	2.21	0.073	0.087			
D	0.76	1.52	0.030	0.060			
Е	5.08	5.59	0.200	0.220			
F	0.051	0.203	0.002	0.008			
G	0.15	0.31	0.006	0.012			
Н	2.11	2.44	0.083	0.096			
J	6.80		0.270				
K		2.60		0.100			
L	2.40		0.090				

## **REEL SPECIFICATION**

P/N	PKG	QTY
ES3AB THRU ES3JB	SMB	3000



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